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Recent Advancements in Semiconductor-based Optical Signal Processing

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Abstract Significant advancements in technology and basic understanding of device physics are bringing optical signal processing closer to a commercial breakthrough. In this paper we describe the main challenges in high-speed SOA-based switching.

Introduction

All-optical signal processing based on resonant nonlinearities in semiconductors has been heavily investigated for more than a decade. As a research topic it is still very active and the last couple of years have witnessed a number of significant advancements, e.g. the demonstration of wavelength conversion at 320 Gb/s using a semiconductor optical amplifier (SOA) combined with a filter [1] and a monolithically integrated, potentially fast all-optical flip-flop [2]. These results illustrate two important points, namely 1) that the technology can certainly meet the bandwidth requirements for ‘simple’, pipelining-like applications such as wavelength conversion, and 2) the path to micro-photonic, very-large scale integration has been shown, with a flip-flop footprint allowing for in excess of 100,000 components per square centimetre [3].

One of the main challenges in bringing optical signal processing to a commercial level is realizing simple, yet fast, schemes that can be integrated in large numbers (either monolithically or hybridly on a motherboard of a different substrate), while keeping the power consumption low. The latter is crucial, since signal processing will be carried out on a per-channel basis, which means that e.g. wavelength division multiplexing (WDM) routers will require a multitude of optical signal processing circuits. Since the electrical and optical power consumption increases with the bitrate it is imperative that the building blocks - the optical switches - use as little power as possible, since this will improve the scalability of the circuits.

Switches based on cross-phase modulation in SOAs have the best potential in terms of power consumption, since they provide gain for the switching signal [4]. In addition, they can be operated in a so-called differential mode [5], enabling operation at bitrates far beyond the inverse carrier lifetime. However, even in this case the impact of the finite carrier lifetime cannot be neglected, as it leads to a so-called nonlinear patterning (NLP) effect, which manifests as a fluctuation of the pulse energy of the switched bits [6]. Recent results show that the ultra-fast nonlinearities play an important role in limiting the NLP [7,8].

In this paper we will review the recent advancements in SOA-based optical signal processing schemes and their integration, with an emphasis on approaches to increase the modulation bandwidth and reducing detrimental effects such as patterning effects and noise accumulation. We show examples from our own research on all-optical switches based on optical equalization of the slow SOA response.

Patterning effects and noise

The modulation of the carrier density in the active region of an SOA, and thus the patterning effect, is described by the carrier rate equation, which in its simplest form, in terms of the gain $g$, reads [6]

$$\frac{dg}{dt} = \frac{g(t) - g_0}{\tau_e} - k g(t) P_c(t)$$

(1)

where $k$ is a constant and $g_0$, $\tau_e$, $P_c(t)$, and $g(t)$ are the small-signal material gain, effective carrier lifetime, control signal, and gain change due to saturation, respectively.

![Fig. 1. (a) Calculated probe phase response to 40 Gb/s control signal, excluding nonlinear term in eq. (1) (solid), and including both terms (dashed). (b) DISC layout. (c) Phase difference between AMZI arms with (dashed) and without (solid) nonlinear term of eq. (1).](image)

The two last terms of eq. (1) act as the driving terms for the dynamics of the gain. However, there is a major difference between the two, in that the first term, $kg_P(t)$, is linear in the modulation, whereas the second term, $kg(t)P_c(t)$ is nonlinear. Ignoring the
nonlinear term due to saturation, reduces eq. (1) to a linear equation, which can be analyzed using standard small-signal analysis of the carrier density modulation (CDM) [6]. A small-signal analysis accurately describes patterning effects attributable to the finite τ, in cases where saturation does not influence the patterning, such as cross-gain modulation (XGM). This effect will be referred to as the linear patterning effect, which manifests as inter-symbol interference. The problem of linear patterning can be reduced by launching a so-called holding beam into the SOA, which reduces the effective carrier lifetime [9,10]. Simply increasing the CW probe input power has a similar impact. However, another possibility is to operate SOA-based interferometric switches in the differential mode (DM) [5,11], which effectively cancels the slow recovery of the carrier density induced gain and phase changes. This is illustrated in Fig. 1, where (a) shows the phase shift imposed on a continuous wave (CW) probe by a 40 Gb/s control signal (shown in top inset) through cross-phase modulation (XPM), in the case where the nonlinear term of eq. (1) is ignored (solid line), and the more realistic case where both terms are included (dashed line). Notice that when saturation is neglected, all control pulses provide the same phase shift, whereas this is not the case when saturation is taken into account. In the DM-switch referred to as the delayed-interference signal converter (DISC), Fig. 1 (b), the phase modulated probe is passed through an asymmetric MZI (AMZI) filter, which converts the phase modulation into amplitude modulation. The transmittance of the filter is determined by the phase difference between the two arms, shown in Fig. 1 (c), excluding the nonlinear term (solid), and including both terms (dashed). It is observed that the linear patterning, induced by the linear driving term of eq. (1), is completely compensated for after the AMZI, whereas the nonlinear term of eq. (1) introduces a clear modulation on the phase difference. The latter is the nonlinear pattern (NLP) effect, which is the only patterning effect remaining after elimination of linear patterning using the DM technique. NLP manifests itself as a fluctuation of the switched pulse power.

In [6] we presented a general approach to analyze the small-signal frequency response (SSFR) of an SOA followed by an optical filter, which optically equalizes the low-pass carrier density response (CDR) of the SOA. As a special case the DISC, i.e. an SOA+AMZI filter, has been analyzed, and the corresponding calculated SSFR is shown in the dashed curves of Fig. 2 for different values of the AMZI phase bias φ. The AMZI is observed to compensate for the low-pass CDR up to a bandwidth determined by the differential delay time, τ, in the AMZI [6].

Experimental data, also shown in Fig. 2, are measured for exactly the same values of phase bias φ, and are observed to match the theoretical results very well in the frequency range up to 20 GHz that could be measured [12]. Notice the comparison with the low-pass CDR. Fig. 2 shows the SSFR normalized to the response at ω = 0. To obtain a flat response up to ultra-high frequencies, the attenuated high frequency contents of the probe signal at the SOA output is enhanced by the AMZI, at the expense of the low-frequency components, which contain the most power. This leads to an inevitable trade-off between modulation bandwidth and optical signal-to-noise ratio (OSNR) [6,13].

The theory presented in [6] is completely general and can be applied to any optical filter. Fig. 3 (a) shows small-signal measurements for a 0.38 nm wide (FWHM) band-pass filter (BPF) when changing the detuning, Δdet, towards the blue side. The normalized response becomes increasingly flat as |Δdet| is increased, and is completely flat (up to 20 GHz, at least) for a detuning of -0.27 nm. Theory predicts that the response becomes flat for a filter slope of 37.7 dB/nm, which is exactly the slope.
measured for a filter detuning of -0.27 nm [7]. Fig. 3 (b) shows large-signal equivalents of the SSFR traces in Fig. 3 (b), in terms of switched output pulse traces, obtained by replacing the small-signal modulation by a 10 GHz train of 2 ps wide pulses. The impact of blue-shifting the BPF in the large-signal regime is observed by following the waveforms from the bottom and up: the recovery time is clearly reduced, and for \( \Delta \nu_{\text{det}} = -0.27 \) nm the inverted pulse is completely symmetric, indicating that the recovery time is as short as the fall-time. Increasing the blue-shift to \( \Delta \nu_{\text{det}} = -0.366 \) nm and beyond, the polarity of the switched signal starts re-inverting, because the power in the carrier-peak, which determines the power in the mark-level of the inverted signal, is increasingly suppressed compared to the power in the blue sideband. This effect is also shown and explained in [13]. For \( \Delta \nu_{\text{det}} = -0.798 \) nm the carrier peak is suppressed by roughly 25 dB, which is sufficient to generate a switched signal with the same polarity as the control signal, and an extinction ratio of 8 dB.

In [14], the complex filter transfer function required to restore the pulse shape of a switched 40 Gb/s signal was calculated, and the filter successfully realized in MEMS technology. Another recently proposed switch configuration, which reduces the NLP imposed on the probe by the control signal has been dubbed the Turbo-Switch [15]. It involves passing the probe through an additional SOA after removing the control signal by a filter. Essentially, the second SOA works as high-pass filter, as described in e.g. [16,17], thereby speeding-up the total probe response. Using this scheme in a hybrid DISC configuration, wavelength conversion at 170 Gb/s was demonstrated with a high output OSNR of 40 dB@0.1 nm. The large OSNR is an advantage of this scheme over the, simpler, configuration of a single SOA and a detuned BPF, described above.

**Impact of ultra-fast dynamics**

Although it is possible to use the differential mode [18,19] as well as the detuned filter approach [20] to enhance the response of a switched NRZ signal, the lack of conveniently available NRZ signals above 50 Gb/s has so far prevented a thorough analysis of NRZ switching. As a result, all ultra-high-speed (>50 Gb/s) demonstrations have been carried out with RZ control signals, typically generated from 10 GHz trains of short pulses.

![Fig. 4. Experimental 105 Gb/s XGM traces for (a) \( \tau_p = 1.8 \) ps and (b) \( \tau_p = 8.0 \) ps. Simulated traces incl. (solid) and excl. (dashed) ultra-fast dynamics for (c) \( \tau_p = 1.8 \) and (d) \( \tau_p = 8.0 \).](image)

As analyzed in detail in [21,22], ultra-fast nonlinearities, such as carrier heating and spectral hole-burning, are excited when the control pulse width is below a certain critical width \( \tau_{\text{cr}} \). Several independent references point to the importance of ultra-fast carrier dynamics in switching schemes based on an SOA followed by a filter [7,8].

Fig. 4 (a) and (b) shows a comparison between experimentally obtained cross correlation traces of cross-gain modulated probe signals for data pulse widths of \( \tau_p = 1.8 \) ps and 8 ps, respectively. In both cases the input is a periodic 105 Gb/s "1011010000" data signal with an energy of 133 fJ/pulse. In Fig. 4 (a) two distinct time scales are observed during gain recovery: an ultra-fast recovery immediately after the control pulses, followed by the much slower inter-band carrier relaxation. In Fig. 4(b), where \( \tau_p \approx \tau_{\text{cr}} \), the fast component is hardly visible. For comparison, traces simulated using the same input powers as in the experiment are shown in Fig. 4 (c) for \( \tau_p = 1.8 \) ps and in Fig. 4 (d) for \( \tau_p = 8.0 \) ps. The XGM traces are shown with (solid) and without (dashed) ultra-fast effects to emphasize that the excellent agreement with the experimental traces relies on the inclusion of nonlinear gain suppression.

The additional gain saturation caused by ultra-fast effects reduces the carrier density depletion by reducing the control pulse energy and thus the stimulated recombination rate [23]. The fact that the amount of carriers depleted per data pulse is diminished prompts a reduction of the carrier density dependent contribution to NLP for the DISC switch configuration (see Fig. 1). In addition, the ultra-fast dynamics can be shown to actually increase the switched output power and thereby the OSNR [7]. This, along with the AMZI filter’s in-band noise filtering [24] ensures a satisfactory signal-to-noise ratio even at ultra-high bitrates. The current speed record for SOA-based switching is 320 Gb/s, which was obtained using a concatenation of detuned bandpass filters and an AMZI filter [1].
Switches based on a single SOA and a sharp filter are difficult to integrate, since a sharp filter typically requires several filter stages, which makes it bulky and potentially lossy. However, the AMZI has been integrated with an SOA to realize an integrated version of the DISC switch, operating at 160 Gb/s [28]. More complex filters have been used for FM → AM conversion in other contexts [29], so a sharp, asymmetric filter response, as the one exploited in [1], could be realized on-chip.

Summary & Discussion
Recent advancements in all-optical, SOA-based signal processing have been reviewed, with an emphasis on simple, high-speed switches, which candidate as building blocks in future advanced optical processing circuits.

References
1. Y. Liu et al., OFC'06, PDP28 (2006)
4. A. Poustie, ECOC'05, WE3.5.1 (2005)
5. K. Tajima et al., JAP 32, p. 1746 (1993)
15. R. J. Manning et al., OFC'06, OWS8 (2006)
22. A. Meccozzi et al., JSTQE 3, p.1180 (1997)
25. V. Lal et al., ECOC'05 PDP 4.3.1 (2005)
26. G. Maxwell et al., ECTC'05 (2005)
27. G. Maxwell et al., ECOC'05 PDP 4.2.2 (2005)